



GTU  
Electronics Engineering

ELEC 331  
Electronic Circuits 2

Fall Semester

**Instructor:** Assist. Prof. Önder Şuvak

HW 1  
Questions and Answers

Updated October 20, 2017 - 13:33

Assigned:

Due:

Answers Out:

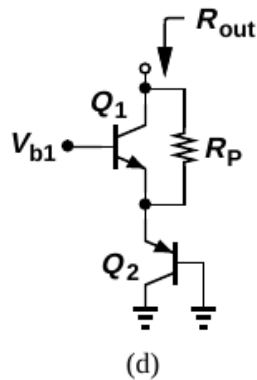
Late Due:

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**BJT Cascode Active Load****Razavi 9.11 d**

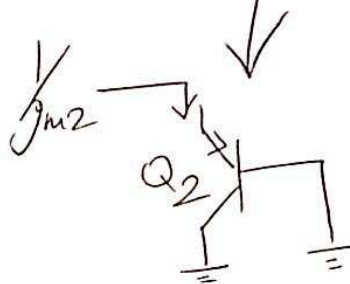
11. Determine the output impedance of each circuit shown in Fig. 9.46. Assume  $\beta \gg 1$ . Explain which ones are considered cascode stages.



**Necessary Knowledge and Skills:** Output impedance calculation, BJT cascode stage properties, relatively high impedance

Prasanna  
9.11d

$$R_{out} = \left(1 + g_{m1} [r_{o1} \parallel R_p]\right) \left[ r_{\pi 1} \parallel \frac{1}{g_{m2}} \right] + [r_{o1} \parallel R_p]$$



—

This is not a cascode stage.

## Active-Loaded MOS Amplifier

Razavi 9.68

68. The common-gate stage of Fig. 9.83 employs the current source  $M_3$  as the load to achieve

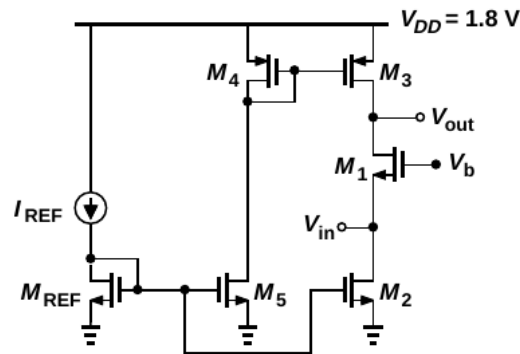


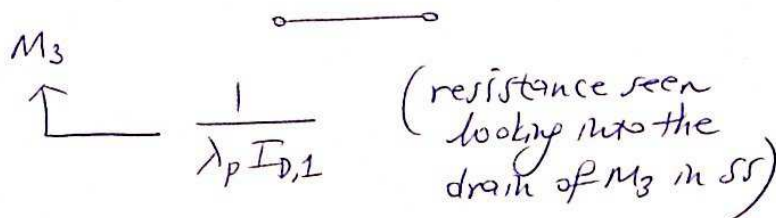
Figure 9.83

a high voltage gain. For simplicity, neglect channel-length modulation in  $M_1$ . Assuming  $(W/L)_3 = 40/0.18$ ,  $\lambda_n = 0.1 \text{ V}^{-1}$ , and  $\lambda_p = 0.2 \text{ V}^{-1}$ , design the circuit for a voltage gain of 20, an input impedance of  $50 \Omega$ , and a power budget of 13 mW. (You may not need all of the power budget.)

**Necessary Knowledge and Skills:** Current mirrors, DC bias computation, common-gate amplifier design, voltage gain and input impedance computations, power budget considerations

note that  $I_{D,1} = I_{D,2} = I_{D,3}$   
 $I_{D,4} = I_{D,5}$

Razani  
9.68



$$\underline{(1)} \quad \frac{v_{out}}{v_{in}} \approx g_{m1} r_{o3} = \sqrt{2 \mu_n C_{ox} \left(\frac{W}{L}\right)_1 I_{D,1}} \cdot \frac{1}{\lambda_p I_{D,1}} = \underline{20 \text{ specif}}$$

$$\underline{(2)} \quad r_{in} \approx \frac{1}{g_{m1}} \parallel r_{o2} \approx \frac{1}{g_{m1}} = \underline{50 \Omega \text{ specif}}$$

$$\nRightarrow \frac{1}{g_{m1}} \gg r_{o2}$$

$$\Rightarrow \text{check } r_{o2} = \frac{1}{\lambda_n I_{D,2}} \quad \left( \text{check this later } \underline{(3)} \right)$$

$$\frac{v_{out}}{v_{in}} = \frac{1}{50 \Omega} \cdot \left( \frac{1}{\lambda_p I_{D,1}} \right) = 20 \quad \left( \text{see } \underline{(1)} \text{ and } \underline{(2)} \text{ above} \right)$$

$$I_{D,1} = \frac{1}{(\lambda_p)(1k\Omega)} = \frac{1}{(0.2V^{-1})(1k\Omega)} = \frac{5V}{1k\Omega} = 5mA$$

now check (3)

$$\frac{1}{\lambda_n I_{D,2}} = \frac{1}{\lambda_n I_{D,1}} = \frac{1}{(0.1 \text{ V}^{-1})(5 \text{ mA})}$$

$$= \frac{10 \text{ V}}{5 \text{ mA}} = 2 \text{ k}\Omega$$

Razavi  
9.68  
continued

Observe that  $2 \text{ k}\Omega \gg 50 \Omega$

then  $\frac{1}{g_{m1}} \parallel r_{o2} \approx \frac{1}{g_{m1}}$  is justified.

$$g_{m1} = \sqrt{2 \mu_n C_{ox} \left(\frac{W}{L}\right)_1 I_{D,1}} = \frac{1}{50 \Omega} = 20 \text{ mS}$$

$$\left(\frac{W}{L}\right)_1 = \frac{(5 \times 10^{-3} \text{ A}) \cdot (100 \times 10^{-9} \text{ A/V}^2)}{(5 \text{ mA}) \cdot 100 \mu\text{A/V}^2 \cdot \sqrt{2}} = 400 \times 10^{-6} \text{ V}^2$$

$$\left(\frac{W}{L}\right)_1 = 400 = \left(\frac{72}{0.18}\right)$$

Remember the parameters

$$\mu_n C_{ox} = 100 \mu\text{A/V}^2$$

$$\mu_p C_{ox} = 50 \mu\text{A/V}^2$$

$$V_{th,n} = 0.4 \text{ V}$$

$$V_{th,p} = -0.5 \text{ V}$$

$$\frac{\text{pow. budget}}{V_{DD}} = \frac{13 \text{ mW}}{1.8 \text{ V}} \approx 7.2 \text{ mA}$$

Remaining  
9.68  
cont.

5 mA expended in the final branch

Let the other branches have 1 mA each flow through them.

then  $I_{\text{ref}} = 1 \text{ mA}$

$I_{D,4} = I_{D,5} = 1 \text{ mA}$

Mref transistor

$$I_{\text{ref}} = \frac{1}{2} \mu_n C_{ox} \left( \frac{W}{L} \right)_{\text{ref}} (V_{G1,\text{ref}} - V_{th,n})^2$$

$\downarrow$        $\downarrow$        $\downarrow$   
 1 mA    100  $\mu\text{A/V}^2$     ?     $\underbrace{V_{G1,\text{ref}}}_{\text{set } 0.6 \text{ V}} - \underbrace{V_{th,n}}_{0.4 \text{ V}}$

$$\frac{2 \times 10^{-3}}{100 \times 10^{-6}} \times \frac{1}{0.04 \text{ V}^2} = \left( \frac{W}{L} \right)_{\text{ref}}$$

$$= 500$$

$$= \frac{90}{0.18}$$



Current mirror of  $M_{ref} - M_5$   
(1mA) (1mA)

$M_{ref}$  and  $M_5$  should be  
of the same size -

$$\left(\frac{W}{L}\right)_{ref} = \left(\frac{W}{L}\right)_5 = 500 = \left(\frac{90}{0.18}\right)$$

Razavi  
9.68  
Cont -

Current mirror of  $M_4 - M_3$   
(1mA) (5mA)

$$\left(\frac{W}{L}\right)_3 = \frac{40}{0.18} \quad \left(\frac{W}{L}\right)_4 = \frac{8}{0.18}$$

$M_4$  ( $V_{SG4}$  computation)

$$I_{D,4} = \frac{1}{2} \underbrace{\mu_p C_{ox}}_{50 \mu A/V^2} \underbrace{\left(\frac{W}{L}\right)_4}_{\frac{8}{0.18}} \underbrace{\left(V_{SG} - |V_{th,p}|\right)^2}_{0.5V^2}$$

$$\frac{1mA}{405} = \frac{1}{2} \times \frac{50 \times 10^{-6} A}{V^2} \times \frac{8}{0.18} \times \left(V_{SG} - 0.5\right)^2$$

$$0.9 = \left(V_{SG} - 0.5\right)^2$$

$$0.95 + 0.5 = V_{SG,4} = 1.45V$$

$$V_{SG,4} = V_{SD,4} = 1.45V$$

M<sub>3</sub> mode check

Reason  
9-68  
cont.

note  $V_{DS} > V_{GS} - V_{th,n}$  (NMOS) for satur.

and  $V_{SD} > V_{SG} - |V_{th,p}|$  (PMOS) for satur.

Observe  $V_{SG,4} = V_{SG,3}$  ( $M_4 - M_3$  is a cur. mirror)

$V_{SD,3} > 1.45 - 0.5$   
 $> 0.95V$  } for  $M_3$  to remain in saturation

M<sub>5</sub> - mode check

note  ~~$V_{DS,5}$~~   $V_{GS,ref} = V_{GS,5}$

then  $V_{DS,5} > V_{GS,5} - V_{th,n}$

$V_{DS,5} > 0.6 - 0.4 = 0.2V$

But we have  $V_{SD,4} + V_{DS,5} = V_{DD} = 1.8V$   
 $\underbrace{1.45V}_{\text{(see the previous page)}} + \underbrace{0.35V}_{> 0.2V}$

then  $M_5$  will be in saturation.

M<sub>2</sub>-size computation

note  $M_{ref} - M_2$  is a current mirror  
 $(1\mu A) \quad (5\mu A)$

Razavi  
 9.68  
 cont.

$$M_2\text{-size} \left(\frac{W}{L}\right)_2 = 5 \left(\frac{W}{L}\right)_{ref} = \frac{450}{1.8}$$

Recall

$$V_{DS,3} > 0.95V \text{ for sat}$$

$$V_{DS,2} > 0.2V //$$

V<sub>GS,1</sub> computation

$$g_{m,1} = \frac{1}{50\Omega} = \frac{2 I_{D,1}}{V_{GS,1} - V_{th,n}}$$

$$= \frac{2 \cdot 5\mu A}{V_{GS,1} - 0.4V}$$

$$\Rightarrow V_{GS,1} - 0.4V = 0.5V$$

$$V_{GS,1} = 0.9V$$

→ need to set a  $V_b$  value to  
 place  $M_3, M_1, M_2$  in sat.

$$\text{set } V_{S1} = 0.25V$$

$$\Rightarrow V_{DS,2} = 0.25V > 0.2V$$

(M<sub>2</sub> in sat.)

$$V_b = \underbrace{V_{S1}}_{0.25V} + \underbrace{V_{GS,1}}_{0.9V} = 1.15V$$

$$\Rightarrow V_{DS,1} > \underbrace{0.5V}_{V_{GS,1} - V_{th,n}} \text{ for satur.}$$

$$\Rightarrow \underbrace{V_{D,1}}_{(V_{S1} + V_{DS,1})} > \underbrace{0.75V}$$

$$\Rightarrow V_{SD,3} < 1.05V$$

since  $V_{DD} = 1.8V = V_{SD,3} + V_{D,1}$

$$\Rightarrow \text{We needed to have } V_{SD,3} > 0.95V \text{ then O.K.}$$

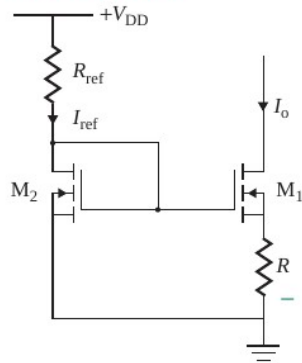
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## MOS Widlar Current Source

Rashid 9.6

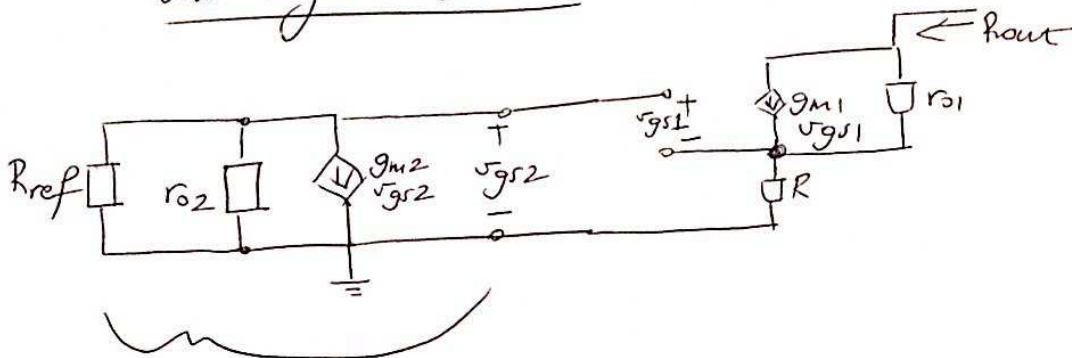
- 9.6** The Widlar current source shown in Fig. P9.6 has  $I_{\text{ref}} = 50 \mu\text{A}$ ,  $R = 2 \text{ k}\Omega$ , and  $V_{\text{DD}} = 12 \text{ V}$ . The MOS parameters are  $K_n = 100 \mu\text{A}/\text{V}^2$ ,  $V_t = 1 \text{ V}$ ,  $|V_M| = 100 \text{ V}$ , and  $(W/L)_1 = (W/L)_2 = 20$ . Determine (a) the output current  $I_o$ , (b) the output resistance  $r_{o2}$ , and (c) the value of  $R_{\text{ref}}$ .

FIGURE P9.6

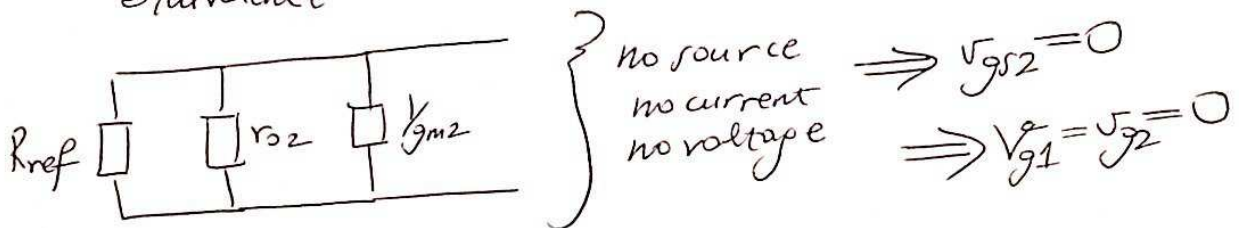


**Necessary Knowledge and Skills:** Widlar current source, DC bias computation, small-signal model and approximations, output impedance calculation

Rashid 9.6

Small signal equivalent

equivalent to



$$R_{out} = (1 + g_{m1} r_{o1}) R + r_{o1}$$

$$\text{check} \Rightarrow v_x = (\bar{v}_x - g_{m1} v_{gs1}) r_{o1} - v_{gs1}$$

$$v_{gs1} = -\bar{v}_x R$$

$$v_x = \bar{v}_x [1 + g_{m1} R] r_{o1} + R \bar{v}_x$$

$$\frac{v_x}{\bar{v}_x} = R_{out} = (1 + g_{m1} R) r_{o1} + R$$

$$= (1 + g_{m1} r_{o1}) R + r_{o1}$$

$$I_D = K_n (V_{GS} - V_t)^2$$

$$\Downarrow$$

$$\frac{1}{2} \mu_n C_{ox} \frac{W}{L}$$

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Problem 9.6  
continued

$$g_m = \frac{2I_D}{2V_{GS}} = 2K_n (V_{GS} - V_t)$$

DC analysis of  $M_2$

$$\begin{aligned} \text{KVL} \Rightarrow V_{DD} &= R_{ref} I_{ref} + V_{DS2} \\ &= R_{ref} \underbrace{I_{ref}}_{= I_{D2}} + V_{GS2} \end{aligned}$$

(no current into the gates)  
DC

$$V_{DD} = R_{ref} \left[ K_n (V_{GS2} - V_t)^2 \right] + V_{GS2} \Rightarrow \text{quadratic eqn solve for } V_{GS2}$$

Note that the  $I_{D2}$ - $V_{GS2}$  saturation current eqn assumption is valid since  $M_2$  will always be in satur.

$$g_{m2} = 2K_n (V_{GS2} - V_t)$$

$$r_{o2} = \frac{|V_A|}{I_{D2}}$$

DC analysis of  $M_1$  (assuming  $M_1$  will be in satur.)

$$\frac{V_{GS2} - V_{GS1}}{R} = I_{D1} = K_n (V_{GS1} - V_t)^2$$

$\Downarrow$   
 $I_O$

solve for  $V_{GS1}$  and then  $I_{D1} = I_O$

assumption that must hold for  $M_1$  to be in satur  $\Rightarrow V_{DS1} \geq V_{GS1} - V_t$   
 $V_{D1} - RI_O \geq V_{GS1} - V_t$  (equivalently)

Generated by CamScanner

Problem 9.6  
continued

equivalently  
for  $M_1$  satur.  $\Rightarrow V_{D1} - RI_0 \geq (V_{GS2} - RI_0) - V_t$

$$V_{D1} \geq V_{GS2} - V_t$$

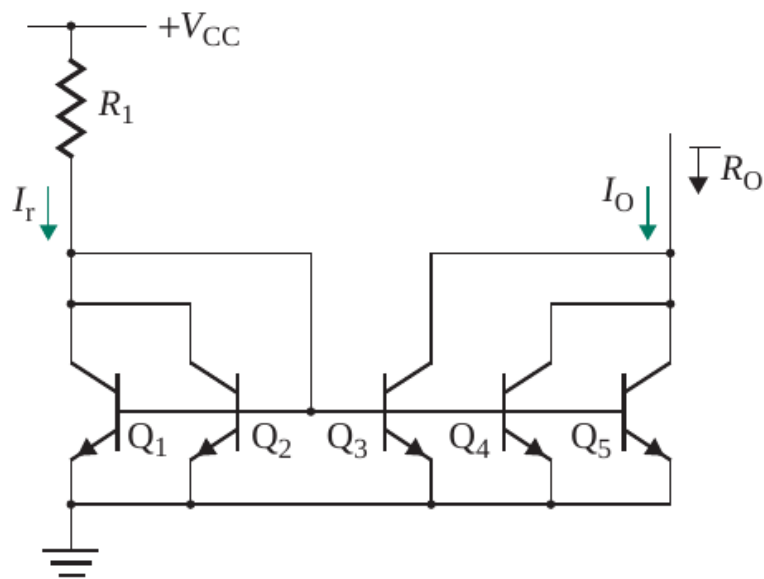
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Note that numerical values are left  
to be computed.



**BJT Current Mirrors****Rashid 9.26**

- 9.26** The multiple transistors of the current source in Fig. P9.26 have  $\beta_F = 150$ ,  $R_1 = 10 \text{ k}\Omega$ ,  $V_{CC} = 15 \text{ V}$ , and  $V_A = 100 \text{ V}$ . The B-E voltages are equal,  $V_{BE} = 0.7 \text{ V}$ . Calculate (a) the output current  $I_O$ , (b) the output resistance  $R_O$ , (c) Thevenin's equivalent voltage  $V_{Th}$ , and (d) the collector current ratio if  $V_{CE2} = 15 \text{ V}$ .

**FIGURE P9.26**

**Necessary Knowledge and Skills:** Current Mirrors, small signal equiv. of BJT, output impedance computation, current assembly, Early voltage and its graphical interpretation

Rashed  
9.26

Assuming  $\beta$  is too big:  
base currents are nearly  
zero, they can all be neglected.

$$\frac{V_{CC} - V_{BE}}{R_1} = I_r = \frac{15 - 0.7}{10k}$$

$$= \frac{14.3V}{10k\Omega} = 1.43mA$$

$$I_o = I_r \frac{3}{2} = 1.43 \frac{3}{2} = 2.16mA$$

$$R_o = \frac{V_A}{I_o/3} \parallel \frac{V_A}{I_o/3} \parallel \frac{V_A}{I_o/3}$$

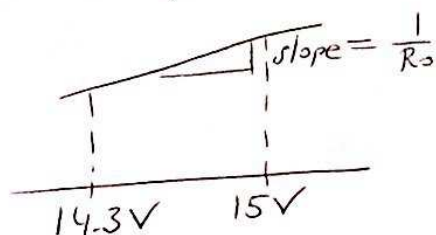
$$= \frac{V_A}{I_o} = \frac{100V}{2.16mA} \text{ (compute)}$$

$$V_{th} \text{ (Thevenin's equiv voltage)}$$

$$= I_o R_o = V_A = 100V$$

collector current ratio =  $\frac{I_o + \Delta I_c}{I_r} = \frac{3}{2} + \frac{\Delta I_c}{I_r}$

computation

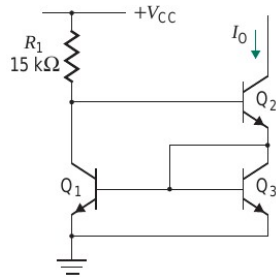


$$\frac{\Delta I_c}{15 - 14.3} = \frac{1}{R_o}$$

$$\Delta I_c = \frac{0.7}{R_o}$$

**Wilson Current Source****Rashid 9.31**

- 9.31** For the Wilson current source in Fig. P9.31, determine the output current  $I_O$  and the output resistance  $R_O$ . Assume  $V_{CC} = 20$  V,  $V_{BE} = 0.7$  V,  $V_T = 26$  mV,  $V_A = 150$  V, and  $\beta_F = 150$ .

**FIGURE P9.31**

**Necessary Knowledge and Skills:** Wilson current source analysis, BJT large and small signal analysis, output impedance computation

compute first  $I_R$  (reference current)  
that flows over  $R_1 = 15k\Omega$

Rashid  
9.31

$$I_R = \frac{V_{CC} - (V_{BE1} + V_{BE2})}{R_1}$$

Note that  $V_{BE1} = V_{BE2} = 0.7V$

$$I_R = \frac{20 - (0.7 + 0.7)}{15k\Omega} = \frac{18.6V}{15k\Omega}$$

$\Rightarrow$  See pages 596-597 in Rashid for the  
derivation of the output current for the  
Wilson current source.

- All the transistors are identical.

$$I_{E2} = I_{C2} \frac{\beta+1}{\beta} = \left(1 + \frac{2}{\beta}\right) \underbrace{I_{C3}}_{I_{C1}}$$

$$I_R = I_{C1} + I_{B2}$$

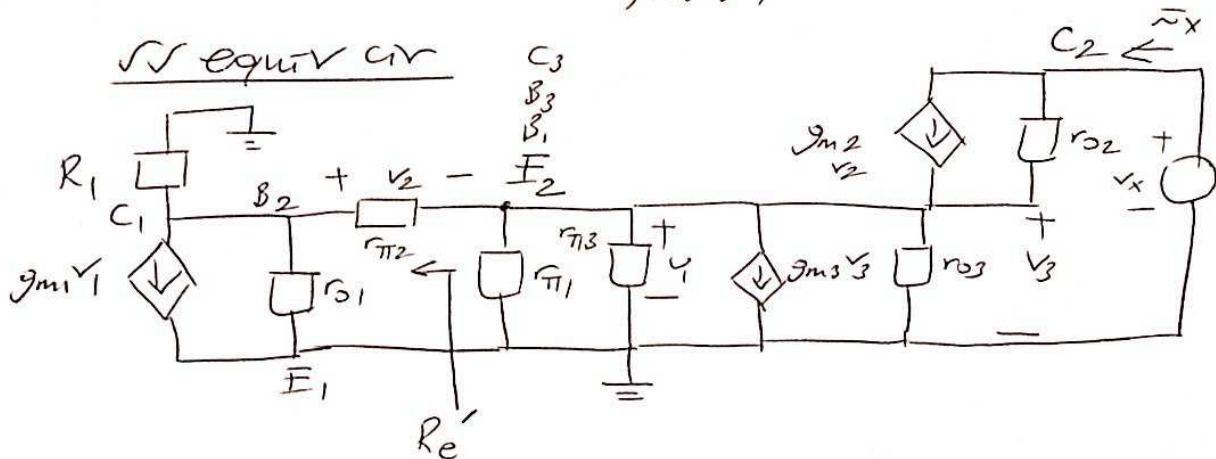
$$= I_{C2} \frac{\beta+1}{\beta} \frac{1}{\left(1 + \frac{2}{\beta}\right)} + I_{C2} \frac{1}{\beta}$$

$$I_R = I_{C2} \left[ \frac{\beta+1}{\beta+2} + \frac{1}{\beta} \right] \Rightarrow \frac{I_{C2}}{I_R} = \frac{\beta(\beta+2)}{\beta^2 + 2\beta + 2} = 1 - \frac{2}{\beta^2 + 2\beta + 2}$$

$\Rightarrow I_R$  computed above,  $\beta$  given, compute  $I_0 = I_{C2}$  **Generated by CamScanner**

For  $R_o$  (output impedance)  
calculation, see  
pp 597-598 of  
Rashid

Rashid  
931  
Continued



note that  $R_e = R_1 \parallel r_{o1}$

then  $R_e' = \frac{v_{x,e2}}{\bar{i}_{x,e2}}$  (connecting a test source at  $\bar{i}_{x,e2}$  node)

$$v_{x,e2} = \bar{i}_{x,e2} \cdot r_{\pi 2} + (\bar{i}_{x,e2} - g_{m1} v_1) R_e$$

$$\rightarrow v_{x,e2} [1 + g_{m1} R_e] = \bar{i}_{x,e2} [r_{\pi 2} + R_e]$$

$$\text{then } R_e' = \frac{r_{\pi 2} + R_e}{1 + g_{m1} R_e}$$

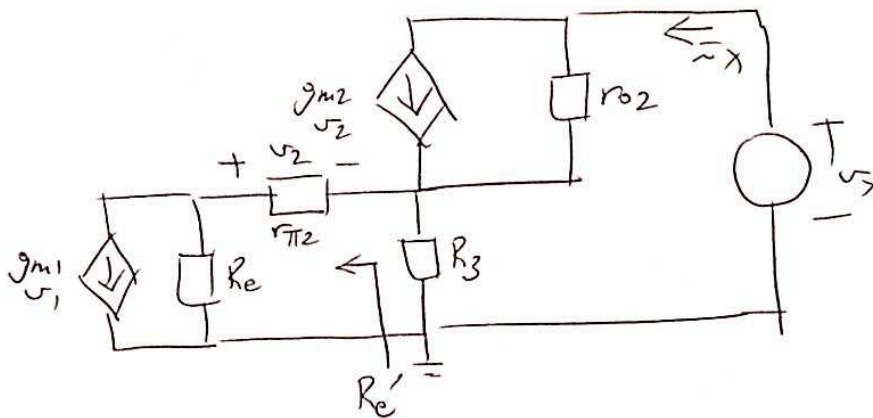
$$R_e' \text{ could be } \approx \frac{1}{g_{m1}} \text{ if } \begin{pmatrix} r_{o1} \gg R_1 \\ R_1 \gg r_{\pi 2} \\ \text{and} \\ g_{m1} R_1 \gg 1 \end{pmatrix}$$

Generated by CamScanner

SS equiv circuit  
simplified

Rashed  
9.31  
Continued

denote by  $R_3 = r_{\pi 1} \parallel r_{\pi 3} \parallel \frac{1}{g_{m3}} \parallel r_{o3} \approx \frac{1}{g_{m3}}$



(KVL)  $v_x = (\bar{v}_x - g_{m2} v_2) r_{o2} + \bar{v}_x [R_3 \parallel R_e']$

$$v_2 = -\bar{v}_x \frac{R_3}{R_3 + R_e'} \cdot r_{\pi 2}$$

$$v_x = \bar{v}_x \left[ r_{o2} + R_3 \parallel R_e' \right] - g_{m2} r_{o2} \left[ -\bar{v}_x \frac{R_3}{R_3 + R_e'} r_{\pi 2} \right]$$

$$\begin{aligned} R_o = \frac{v_x}{\bar{v}_x} &= r_{o2} + \frac{R_3 R_e'}{R_3 + R_e'} + \beta_2 \frac{R_3 r_{o2}}{R_3 + R_e'} \\ &= r_{o2} + \frac{R_3 (R_e' + \beta_2 r_{o2})}{R_3 + R_e'} \end{aligned}$$

(3)

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$$R_o \approx r_{o2} + \underbrace{R_3 // R_{e'}}_{\text{small}} + r_{o2} \beta_2 \left( \frac{R_{e'}}{R_3 + R_{e'}} \right)$$

Practical 9.31  
Continued

$\approx \frac{1}{2}$  if  $\frac{1}{g_{m3}} \approx \frac{1}{g_{m1}}$

then

$$R_o \approx r_{o2} \left( 1 + \frac{\beta_2}{2} \right)$$

$$g_m = \frac{I_c}{V_T}$$

$$g_m r_{\pi} = \beta \Rightarrow r_{\pi} = \beta \frac{V_T}{I_c}$$

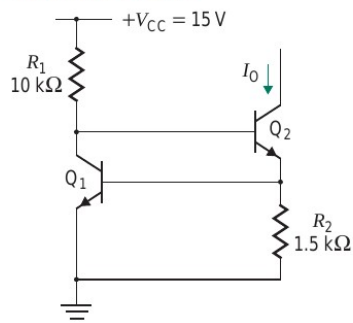
$$\text{and } r_o = \frac{V_A}{I_c}$$

Plug in and compute the numerical values.

**Current Source Sensitivity****Rashid 9.34**

**9.34** Determine the sensitivity  $S$  of output current  $I_O$  to supply voltage  $V_{CC}$  for the circuit in Fig. P9.34.  $S$  is defined as

$$S = \frac{V_{CC}/I_O}{\delta I_O / \delta V_{CC}}$$

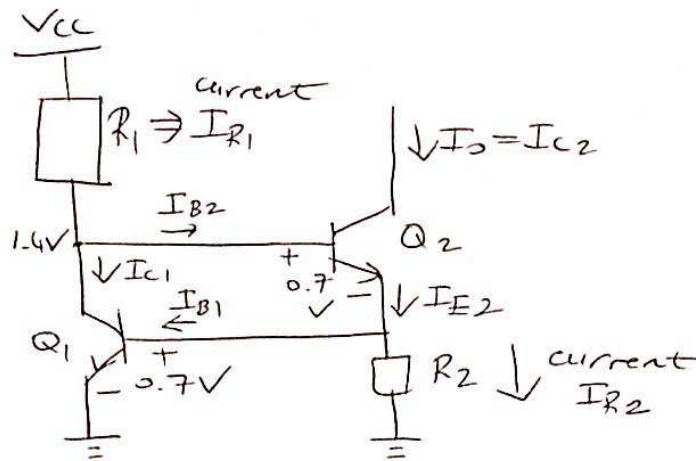
**FIGURE P9.34**

**Necessary Knowledge and Skills:** Sensitivity analysis, BJT current source/reference, BJT large and small signal analysis,



Rashed  
9.34

$$\int_{V_{CC}}^{I_0} \frac{\partial I_0 / I_0}{\partial V_{CC} / V_{CC}} = \frac{2 I_0}{2 V_{CC}} \frac{V_{CC}}{I_0}$$



$$I_{R1} = \frac{V_{CC} - V_{BE1} - V_{BE2}}{R_1}$$

$$I_{R1} = I_{B2} + I_{C1}$$

$$I_{B2} = \frac{I_0}{\beta}$$

$$I_{E2} = I_0 \frac{\beta + 1}{\beta}$$

$$I_{E2} = I_{B1} + \frac{V_{BE1}}{R_2}$$

$$I_{C1} = \beta I_{B1}$$

$$I_0 \frac{\beta + 1}{\beta} - \frac{V_{BE1}}{R_2} = I_{B1}$$

$$I_{C1} = \beta \left[ \frac{\beta + 1}{\beta} I_0 - \frac{V_{BE1}}{R_2} \right]$$

$$= (\beta + 1) I_0 - \frac{\beta V_{BE1}}{R_2}$$

$$V_{CC} = I_{R1} R_1 + V_{BE1} + V_{BE2}$$

$$I_{R1} = \frac{I_0}{\beta} + (\beta + 1) I_0 - \frac{\beta V_{BE1}}{R_2}$$

$$V_{CC} = R_1 \left[ I_0 \left( \frac{1}{\beta} + \beta + 1 \right) - \frac{\beta V_{BE1}}{R_2} \right] + V_{BE1} + V_{BE2}$$

$$(*) I_o = \left[ \frac{V_{CC} - V_{BE1} - V_{BE2}}{R_1} + \frac{\beta V_{BE1}}{R_2} \right] \cdot \left[ \frac{\beta}{\beta^2 + \beta + 1} \right]$$

Rashed  
9.34  
cont.

Considering that  $V_{BE1} \approx V_{BE2} \approx 0.7V$

$$\frac{2I_o}{2V_{CC}} = \frac{1}{R_1} \frac{\beta}{\beta^2 + \beta + 1}$$

then  $\int_{V_{CC}}^{I_o} = \frac{1}{R_1} \frac{\beta}{\beta^2 + \beta + 1} \frac{V_{CC}}{I_o} \rightarrow \text{plug in } (*)$

